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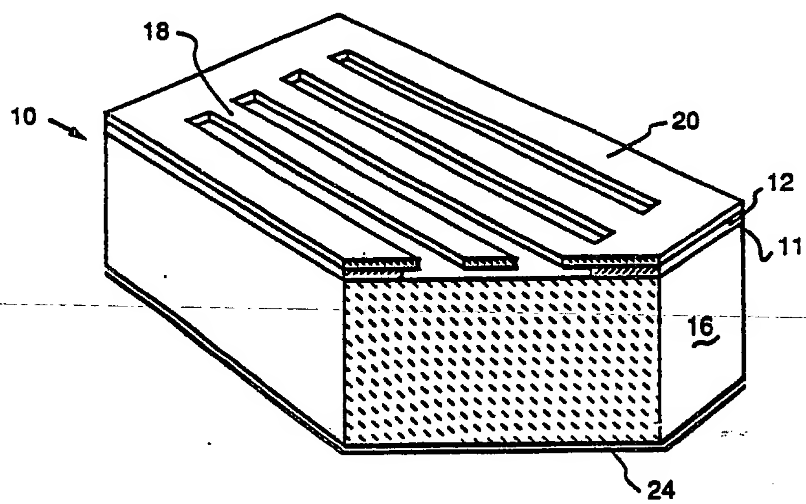

(57) Abstract

A modulator (10) for modulating incident rays of light, the modulator having several equally spaced beam elements (18), each having a light reflective planar surface. The beam elements are arranged and supported (12) parallel to each other, with their reflective surfaces parallel. During operation, the elements remain parallel, but the modulator moves the beams so that the perpendicular spacing of their reflective surfaces changes between two configurations. In both configurations, the spacing equals m/4 times the wavelength of incident light. In the first configuration, m equals an even whole number or zero, and the modulator acts to reflect the incident rays of light as a plane mirror. In the second configuration, m equals an odd number and the modulator diffracts the incident rays as they are reflected.

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A. CLASSIFICATION OF SUBJECT MATTER

IPC(5) :G02B 5/18, 26/00
US CL :359/566,572,573,291

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

U.S. : 359/566,572,573,291 359/231,295,298,299,302,558,569

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

Please See Extra Sheet.

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US,A, 4,596,992 (Hornbeck) 24 June 1986 See col. 7, lines 40+ and col. 8, lines 33+ see Fig. 12C.	1,2,6-8,22 23
X	US,A, 4,492,435 (Banton et al.) 08 January 1985 See Fig. 5.	11,12

☐ Further documents are listed in the continuation of Box C. ☐ See patent family annex.

* Special categories of cited documents:

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B. FIELDS SEARCHED

Electronic data bases consulted (Name of data base and where practicable terms used):

APS Diffract()
Reflect()
Grating Phase Grating
Electrostatic Deform()
Quarter Wave

Specification

MODULATING A LIGHT BEAM

BACKGROUND OF THE INVENTION

Field of the Invention

This invention relates to a method and apparatus for modulating a light beam and more particularly to the use of a reflective, deformable diffraction grating for performing such modulation.

Brief Description of the Prior Art

Devices which modulate a light beam, e.g. by altering the amplitude, frequency or phase of the light, find a number of applications. An example of such a device is a spatial light modulator (SLM) which is an electronically or optically controlled device which consists of one or two-dimensional reconfigurable patterns of pixel elements, each of which can individually modulate the amplitude, phase or polarization of an optical wavefront.

These devices have been extensively developed, particularly for applications in the areas of optical processing and computing. They can perform a variety of functions such as: analog multiplication and addition, signal conversion (electrical-to-optical, incoherent-to-coherent, amplification, etc.), nonlinear operations and short term storage. Utilizing these functions, SLMs have seen many different applications from display technology to optical signal processing. For example, SLMs have been used as optical correlators (e.g., pattern recognition devices, programmable holograms), optical matrix processors (e.g., matrix multipliers, optical cross-bar switches with broadcast capabilities, optical neural networks, radar beam forming), digital optical architectures (e.g., highly parallel optical computers) and displays.

The requirements for SLM technology depend strongly on the application in mind: for example, a display requires low bandwidth but a high dynamic range while

optical computers benefit from high response times but don't require such high dynamic ranges. Generally, systems designers require SLMs with characteristics such as: high resolution, high speed (kHz frame rates), good gray scale high contrast ratio or modulation depth, optical flatness, VLSI compatible, easy handling capability and low cost. To date, no one SLM design can satisfy all the above requirements. As a result, different types of SLMs have been developed for different applications, often resulting in trade-offs.

Texas Instrument, for instance, has developed a "Deformable Mirror Device (DMD)" that utilizes an electromechanical means of deflecting an optical beam. The mechanical motions needed for the operation of the DMD are relatively large and, as a result, the bandwidths are limited to tens of kilohertz. This device, however, gives good contrast ratios and high-resolution and is, furthermore, compatible with CMOS, and other low power technologies.

Nematic and ferroelectric liquid crystals have also been used as the active layer in several SLMs. Since the electrooptic effect in liquid crystals is based on the mechanical reorientation of molecular dipoles, it is to be expected that liquid crystals are faster than the DMD-type devices. Modulators using ferroelectric liquid crystals have exhibited moderate switching speeds (150 μsec to 100 nsec), low-power consumption, VLSI compatible switching voltages (5-10 V), high extinction ratios, high resolution and large apertures. However, these devices suffer from the drawbacks of limited liquid crystal lifetimes and operating temperature ranges. In addition, the manufacturing process is complicated by alignment problems and film thickness uniformity issues.

Magnetooptic modulation schemes have been used to achieve faster switching speeds and to provide an optical pattern memory cell. Although these devices, in addition to achieving fast switching speeds, can achieve large contrast ratios, they suffer from a low (<10%) throughput

efficiency and are, therefore, often unsuitable for many applications.

The need is therefore for a light modulation device which overcomes these drawbacks.

Beside SLMs, another area of use of light modulators is in fiber optics. Fiber optic modulators are electronically controlled devices that modulate light intensity and are designed to be compatible with optical fibers. For high speed communication applications, lithium niobate ($LiNbO_3$) traveling wave modulators represent the state-of-the-art, but there is a need for low power, high efficiency, low loss, inexpensive fiber optic modulators, that can be integrated with silicon sensors and electronics, for data acquisition and medical applications. A typical use of a modulator combined with fiber optic technology, for example, is a data acquisition system on an airplane which consists of a central data processing unit that gathers data from remote sensors. Because of their lightweight and electromagnetic immunity characteristics, fiber optics provide an ideal communication medium between the processor and the sensors which produce an electrical output that must be converted to an optical signal for transmission. The most efficient way to do this is to have a continuous wave laser at the processor and a modulator operating in reflection at the sensor. In this configuration, it is also possible to deliver power to the sensor over the fiber.

In this type of application the modulator should operate with high contrast and low insertion loss to maximize the signal to noise ratio and have low power consumption. It should further be compatible with silicon technology because the sensors and signal conditioning electronics used in these systems are largely implemented in silicon.

Another use of a modulator combined with fiber optic technology is in the monitoring of sensors that are surgically implanted in the human body. Here optical fibers are preferred to electrical cables because of their

galvanic is lation, and any modulator used in these applicati ns should exhibit high contrast combined with low insertion loss because of signal to noise considerations. Furthermore, as size is important in implanted devices, the modulator must be integratable with silicon sensors and electronics.

There exist no prior art devices that have the characteristics enumerated above. Modulators based on the electro-optic, Franz-Keldysh, Quantum-Confined-Stark or Wannier-Stark effect in III-V semiconductors have high contrast and low insertion loss, but are expensive and not compatible with silicon devices. Waveguide modulators employing glass or epi-layers on silicon, require too much area and too complex fabrication to be easily integratable with other silicon devices. Silicon modulators that do not employ waveguides and that are based on the plasma effect, require high electrical drive power and do not achieve high contrast.

The need is therefore for a light modulator which can be used with fiber optic technology with low power, high efficiency, low loss, low cost and compatibility with multimode optical fibers and silicon technology.

SUMMARY OF THE INVENTION

Objects of the Invention

Accordingly, it is an object of this invention to provide a light modulator which alone or together with other modulators exhibits most of the following characteristics: high resolution, high speed (Khz frame rates), gray levels (100 levels), high contrast ratio or modulation depth, optical flatness, VLSI compatible, easy handling capability and low cost.

A further object of this invention is to provide a light modulator which has a tolerance for high optical power and good optical throughput.

Yet another object of this invention is to provide a light modulator which is compatible with CMOS technology.

Still another object of this invention is to provide a light modulator capable of use with fiber optic technology.

A final object of this invention is to provide a light modulator which is capable of modulating white light to produce colored light.

Summary

Briefly a presently preferred embodiment of this invention includes a modulator for modulating incident rays of light, the modulator comprising a plurality of equally spaced apart beam elements, each of which includes a light reflective planar surface. The elements are arranged parallel to each other with their light reflective surfaces parallel to each other. The modulator includes means for supporting the beam elements in relation to one another and means for moving the beam elements relative to one another so that the beams move between a first configuration wherein the modulator acts to reflect the incident rays of light as a plane mirror, and a second configuration wherein the modulator diffracts the incident rays of light as they are reflected therefrom. In operation, the light reflective surfaces of

the beam elements remain parallel to each other in both the first and the second configurations and the perpendicular spacing between the reflective surfaces of adjacent beam elements is equal to m/4 times the wavelength of the incident rays of light, wherein m = an even whole number or zero when the beam elements are in the first configuration and m = an odd number when the beam elements are in the second configuration.

One embodiment of this invention includes a reflective deformable grating light modulator, with a grating amplitude that can be controlled electronically, consisting of a reflective substrate with a deformable grating suspended above it. In its undeformed state, with no voltage applied between the elements of the grating and the substrate, the grating amplitude is one half of the wavelength of the incoming light. Since the round-trip path difference between the light reflected from the top and bottom of the grating is one wavelength, no diffraction occurs. When a voltage is applied between the grating elements and the substrate, the electrostatic force pulls the elements down to cause the grating amplitude to become one quarter of the wavelength so that reflections from the elements and the substrate add destructively, causing the light to be diffracted. If the detection system for the reflected light has a numerical aperture which accepts only the zero order beam, a mechanical motion of only one quarter of a wavelength is sufficient to modulate the reflected light with high contrast.

Typically the grating is formed by lithographically etching a film made of silicon nitride, aluminum, silicon dioxide or any other material which can be lithographically etched.

The deformable grating modulator of this invention has the advantage that it is implemented in silicon technology, using micromachining and sacrificial etching of thin films to fabricate the gratings. Circuitry for addressing and multiplexing can be manufactured on the same silicon substrate and thus be directly integrated

with the modulator. Direct integration with electronics is an important advantage over non-silicon based techn 1 gies like liquid crystal and electrooptic SLMs. Moreover, the device demonstrates simplicity of fabrication and can be manufactured with only a few lithographic steps.

A further advantage of the deformable grating modulator is that because the deformable grating modulator utilizes diffraction rather than deflection of a light beam, the required mechanical motions are reduced from several microns (as in deformable mirror devices) to tenths of a micron, thus allowing for a potential three orders of magnitude in increase in speed. This speed is comparable to the fastest liquid crystal modulators, but without the device suffering the same complexity in the manufacturing process.

Still a further advantage of these devices is that the required motion of the grating elements is only one quarter of a wavelength, which means that elements with high resonance frequencies can be used.

These and other objects and advantages of the present invention will no doubt become apparent to those skilled in the art after having read the following detailed description of the preferred embodiment which is illustrated in the several figures of the drawing.

IN THE DRAWING

This invention will now be further illustrated with reference to the accompanying drawing in which:

FIG. 1(a)-(d) are cross-sections through a silicon substrate illustrating the manufacturing process of a reflective, deformable diffraction grating according to one embodiment of the invention;

FIG. 2 is an isometric, partially cut-away view of the diffraction grating, the manufacture of which is illustrated in FIG. 1.

FIG. 3 illustrates the operation of the grating of FIG. 2 in its "non-defracting" mode;

FIG. 4 and illustrates the operation of the grating of FIG. 3 in its "diffracting" mode;

FIG. 5 is a cross-section similar to that in FIG. 3, illustrating an alternative embodiment of the grating in its "non-defracting" mode;

FIG. 6 is a cross-section similar to that in FIG. 4, illustrating the grating in FIG. 8 in its "defracting" mode;

FIG. 7 is a pictoral view illustrating a further embodiment of the grating;

FIG. 8 is a cross-section along line 8-8 in FIG. 7;

FIG. 9 is a graphical representation of the modulation of a laser beam by the grating of the invention;

FIG. 10 is an illustration of how the diffraction grating of the invention can be combined with other gratings to form a complex modulator; and

FIG. 11 illustrates the operation of the grating in the modulation of colored light.

DESCRIPTION OF PREFERRED EMBODIMENTS

The fabrication steps required to produce a reflective deformable grating 10 according to this invention are illustrated in FIG. 1(a)-(d).

The first step, as illustrated in FIG. 1(a), is the deposition of an insulating layer 11 made of stoichemetric silicon nitride topped with a buffer layer of silicon dioxide followed by the deposition of a sacrificial silicon dioxide film 12 and a low-stress silicon nitride film 14, both 213 nm thick, on a silicon substrate 16. The low-stress silicon nitride film 14 is achieved by incorporating extra silicon (beyond the stoichiometric balance) into the film, during the deposition process. This reduces the tensile stress in the silicon nitride film to roughly 200 MPa.

In the second step, which is illustrated in FIG. 1(b), the silicon nitride film 14 is lithographically patterned into a grid of grating elements in the form of elongate beams 18. In an individual grating, all the

beams are of the same dimension and are arranged parallel to one another with the spacing between adjacent beams equal to the beam width. Depending on the design of the grating, however, beams could typically be 1, 1.5 or 2μm wide with a length that ranges from 10μm to 120μm. After this lithographic patterning process a peripheral silicon nitride frame 20 remains around the entire perimeter of the upper surface of the silicon substrate 16. This frame 20 is further illustrated in FIG. 2 and will be more fully described below with reference to that figure.

After the patterning process of the second step, the sacrificial silicon dioxide film 12 is etched in hydrofluoric acid, resulting in the configuration illustrated in FIG. 1(c). It can be seen that each beam 18 now forms a free standing silicon nitride bridge, 213 nm thick, which is suspended a distance of 213nm (this being the thickness of the etched away sacrificial film 12) clear of the silicon substrate. As can further be seen from this figure the silicon dioxide film 12 is not entirely etched away below the frame 20 and so the frame 20 is supported, a distance of 213 nm, above the silicon substrate 16 by this remaining portion of the silicon dioxide film 12. The beams 18 are stretched within the frame and kept straight by the tensile stress imparted to the silicon nitride film 14 during the deposition of that film.

The last fabrication step, illustrated in FIG. 1(d), is sputtering, through a stencil mask, of a 50 nm thick aluminum film 22 to enhance the reflectance of both the beams 18 and the substrate 16 and to provide a first electrode for applying a voltage between the beams and the substrate. A second electrode is formed by sputtering an aluminum film 24, of similar thickness, onto the base of the silicon substrate 16.

The final configuration of the grating is illustrated in FIG. 2. Here it can be seen that the beams 18 together with the frame 20 define a grating which, as will be later explained, can be used for modulating a light beam. Furthermore, and as can be gathered from the above

described manufacturing process, the frame is formed integrally with the beams 18 and thus provides a relatively rigid supporting structure which maintains the tensile stress within the beams 18. In so doing, and as the frame 20 is supported by the remainder of the silicon dioxide film 12 that was not etched away, the beams are kept straight and a distance of 213 nm above the surface of the silicon substrate 16.

The operation of the deformable grating 10, formed by the above process, is illustrated with reference to FIG. 3 and 4. Before commencing the description of how the grating operates, however, it should be recalled that, in this case, each of the beams 18 are 213 nm thick and are suspended a distance of 213 nm clear of the substrate 16. This means that the distance from the top of each beam to the top of the substrate is 426 nm. Similarly, the distance between the top of the reflective surface on the beams to the top of the reflective surface on the substrate is also 426 nm. This distance is known as the grating amplitude.

In FIG. 3 the grating 10 is shown with no voltage applied between the substrate 16 and the individual beams 18 and with a lightwave, generally indicated as 26, of a wavelength λ = 852 nm is incident upon the it. The grating amplitude of 426 nm is therefore equal to half of the wavelength of the incident light and, therefore, the total path length difference for the light reflected from the beams and from the substrate equals the wavelength of the incident light. As a result, light reflected from the beams and from the substrate add in phase and the grating 10 acts to reflect the light as a flat mirror.

However, as illustrated in FIG. 4, when a voltage is applied between the beams 18 and the substrate 16 the electrostatic forces pull the beams 18 down onto the substrate 16, with the result that the distance between the top of the beams and the top of the substrate is now 213 nm. As this is one quarter of the wavelength of the incident lights, The total path length difference for the light reflected from the beams and from the substrate is

now one half of the wavelength (426 nm) of th incident light and the reflecti ns interfere destructively, causing the light to be diffracted, indicated as 28.

Thus, if this grating is used in combination with a system, for detecting the reflected light, which has a numerical aperture sized to detect one order of diffracted light from the grating e.g., the zero order, this grating can be used to modulate the reflected light with high contrast.

In FIGS. 5 and 6 an alternative embodiment of the diffraction grating 30 of the invention is illustrated. In this embodiment the grating 30 consists of a plurality of equally spaced, equally sized, fixed beams 32 and a plurality of equally spaced, equally sized, movable beams 34 in which the movable beams 34 lie in the spaces between the fixed beams 32. Each fixed beam 32 is supported on and held in position by a body of supporting material 36 which runs the entire length of the fixed beam 32. The bodies of material 36 are formed during a lithographic etching process in which the material between the bodies 36 is removed.

As can be seen from FIG. 5 the fixed beams 32 are arranged to be coplanar with the movable beams 34 and present a flat upper surface which is coated with a reflective layer 38. As such the grating 30 acts as a flat mirror when it reflects incident light, however, when a voltage is applied between the beams and an electrode 40 at the base of the grating 30 the movable beams 34 move downwards as is illustrated in FIG. 6. By applying different voltages the resultant forces on the beams 34 and, therefore, the amount of deflection of the movable beams 34 can be varied. Accordingly, when the grating amplitude (defined as the perpendicular distance $\underline{d}$ between the reflective layers 38 on adjacent beams) is $m/4$ times the wavelength of the light incident on the grating 30, the grating 30 will act as a plane mirror when $m = 0, 2, 4...$ (i.e. an even number or zero) and as a reflecting diffraction grating when $m = 1, 3, 5...$ (i.e. an odd number). In this manner the grating 30 can operate to

modulate incident light in the same manner as the grating 10 illustrated in FIGS. 1 to 4.

Yet another embodiment of the diffraction grating of the invention is illustrated in FIGS. 7 and 8. As with the grating 10 in FIGS. 1 to 4 this grating 41 consists of a sacrificial silicon dioxide film 42, a silicon nitride film 44 and a substrate 46. In this embodiment, however, the substrate 46 has no reflective layer formed thereon and only the silicon nitride film 44 has a reflective coating 45 formed thereon. As is illustrated in FIG. 7 the deformable beams 48 are coplanar in their undeformed state and lie close to one another so that together they provide a substantially flat reflective surface. The beams 48 are, however, formed with a neck 50 at either end, which is off-center of the longitudinal center line of each of the beams 48.

When a uniformly distributed force, as a result of an applied voltage for example, is applied to the beams 48 the resultant force F, for each beam 48, will act at the geometric center 52 of that beam. As each resultant force F is off-set from the axis of rotation 54 (which coincides with the centerline of each neck 50), a moment of rotation or torque is applied to each beam 48 which results in a rotation of each beam 48 about its axis 54 to the position 48′ indicated in broken lines. This is known as "blazing" a diffraction grating.

As can be seen from FIG. 8, the reflective planes 56 of the beams 48 remain parallel to each other even in this "blazed" configuration and therefore, the grating amplitude d is the perpendicular distance between the reflective surfaces of adjacent beams. This "blazed" grating will operate to diffract light in the same manner as a sawtooth grating.

Although not illustrated in any of FIGS. 1 to 8, it will be apparent that a deformable diffraction grating can be constructed in which, in its undeformed state, all the reflective elements are in the form of movable beam elements arranged parallel, adjacent and coplanar with each other. In this type of grating not only the grating

amplitude (i.e., the perpendicular distance between adjacent reflective surfaces) can be varied but also the average height of all the reflective surfaces can be changed by m ving all th beams relative to a fixed datum. This arrangement has the advantage that both the amplitude and the phase of the reflected/diffracted light can be modulated.

The electrical, optical and mechanical characteristics of a number of modulators, similar in design to the modulator illustrated with reference to FIGS. 1 to 4 but of different dimensions were investigated by using a Helium Neon laser (of 633 nm wavelength) focused to a spot size of 36μm on the center portion of each modulator. This spot size is small enough so that the curvature of the beams in the region where the modulator was illuminated can be neglected, but is large enough to allow the optical wave to be regarded as a plane wave and covering enough grating periods to give good separation between the zero and first order diffraction modes resulting from the operation of the grating. It was discovered that grating periods of (i.e.) the distance between the centerlines of two adjacent beams in the grating, 2,3 and 4 μm and a wavelength of 633 nm resulted in first order diffraction angles of 18°, 14° and 9° respectively.

One of these first order diffracted light beams was produced by using a 120 μm-long grating modulator with 1.5 μm-wide beams at atmospheric pressure together with a HeNe light beam modulated at a bit rate of 500 kHz. detected by a low-noise photoreceiver and viewed on an oscilloscope. The resulting display screen 30 of the oscilloscope is illustrated in FIG. 9.

However, before proceeding with a discussion of the features illustrated in this figure, the resonant frequency of the grating elements should first be considered.

The resonant frequency of the mechanical structure of the grating of the invention was measured by driving the deformable grating modulator with a step function and

observing the ringing frequency. The area of the aluminum on the deformable grating modulator is roughly 0.2 cm^2, which corresponds to an RC limited 3-dB bandwidth of 1 MHz with roughly 100 ohms of series resistance. This large RC time constant slowed down the step function, however, enough power existed at the resonant frequency to excite vibrations, even in the shorter beams. Although the ringing could be observed in normal atmosphere, the Q-factor was too low (approximately 1.5) for accurate measurements, so the measurements were made at a pressure of 150 mbar. At this pressure, the Q-factor rose to 8.6, demonstrating that air resistance is the major damping mechanism, for a grating of this nature, in a normal atmosphere.

Nonetheless, it was found that due to the high tensile stress in the beams, tension is the dominant restoring force, and the beams could therefore be modeled as vibrating strings. When this was done and the measured and theoretically predicted resonance frequencies compared, it was found that the theory is in good agreement with the experimental values, particularly when considering the uncertainty in tensile stress and density of the beams. As it is known that the bandwidth of forced vibrations of a mechanical structure is simply related to the resonance frequency and Q-factor, a Q-factor of 1.5 yields a 1.5 dB bandwidth of the deformable grating modulator 1.4 times larger than the resonance frequency. The range of bandwidths for these gratings is therefore from 1.8 MHz for the deformable grating modulator with 120 μm beams to 6.1 MHz for the deformable grating modulator with 40 μm beams.

Returning now to FIG. 9, it should be noted that with an applied voltage swing of 3 V, a contrast of 16dB for the 120 μm-long bridges could be observed. Here the term "modulation depth" is taken to mean the ratio of the change in optical intensity to peak intensity.

The input (lower trace 62) on the screen 60 represents a pseudo-random bit stream switching between 0 and -2.7 V across a set of grating devices on a 1 cm by 1

cm die. The observed switching transient with an initial fast part followed by a RC d minated part, is caus d by the series resistance of the deformable grating modulator, which is comparable to a 50 ohm source resistance.

The output (upper trace 64) on the screen corresponds to the optical output of a low-noise photoreceiver detecting the first diffraction order of the grating used. The output (upper trace 64) from the deformable grating is high when the beams are relaxed and low when the beams are deflected. Ringing is observed only after the rising transient, because of the quadratic dependence of the electro-static force on the voltage (during switching from a voltage of -2.7 V to 0 V, the initial, faster part of the charging of the capacitor corresponds to a larger change in electro-static force, than when switching the opposite way). This ringing in the received signal indicates a decay close to critical damping.

Furthermore, it was found that because the capacitance increases as the beams are pulled toward the substrate, the voltage needed for a certain deflection is not a monotonically increasing function of this deflection. At a certain applied voltage condition, an incremental increase in the applied voltage causes the beams to be pulled spontaneously to the substrate (to latch) and this voltage is known as the "switching voltage" of the modulator. The switching voltage was found to be 3.2 V for gratings with 120 μm long beams and, if it is assumed that tension dominates the restoring forces, the switching voltage is inversely proportional to the beam length and therefore, the predicted switching voltage for 40 μm long beams will be 9.6 V.

The importance of the switching voltage is that below this voltage, the deformable grating modulator can be operated in an analog fashion, however, if a voltage greater than the switching voltage is applied to the modulator it acts in a digital manner. Nonetheless, it is important to note that operating the modulator to the point of contact is desirable from an applications point of view, because as discussed above when the beams are

deflected electrostatically, an instability exists once the beam deflection goes beyond the halfway point. This results in hysteretic behavior which will "latch" the beam in the down position. This latching feature gives the modulator the advantages of an active matrix design without the need for active components. A further advantage of this latching feature is that once the beam has "latched" it requires only a very small "holding voltage", much smaller than the original applied voltage, to keep the beam in its latched configuration. This feature is particularly valuable in low power applications where efficient use of available power is very important.

Finally, it was discovered that when the beams of the modulators are brought into contact with the substrate they could stick. This can be solved by adding small ridges below the beams to reduce the contact area between the beams and the substrate and thereby reduce the sticking problem.

The use of the modulator of this invention in displays requires high yield integration of individual modulator elements into 2-D arrays such as that illustrated in FIG. 10 which shows a plurality of grating modulators which can be used to provide a gray-scale operation. Each of the individual modulators 66, 68, 70, 72 consist of a number of beams and gray-scale can be obtained by addressing each modulator in a binary-weighted manner. The hysteresis characteristic for latching (as described above) can be used to provide gray-scale variation without analog control of the voltage supplied to individual grating modulator elements.

In FIG. 11 the use of the grating, in combination with other gratings, for modulating white light to produce colored light is illustrated. This approach takes advantage of the ability of a grating to separate a light spectrum into its consistent colors. By constructing separate red, green and blue modulation elements each with a grating designed to diffract the appropriate color into an optical system, a color display which is white light

illuminated can be achieved. This approach is attractive f r large area projecti n displays.

In summary, the reflective, def rmable grating light modulator of this inventi n is a device which exhibits high resolution (40 by 40 μm^2 to 100 μm^2); high response times/large bandwidth (2 to 6 MHz); high contrast ratio (close to 100% modulation with a 3V switching voltage); is polarization independent and easy to use. This device also has tolerance for high optical power, has good optical throughput, is simple to manufacture, CMOS compatible, and has application in a wide range of fields including use as an SLM and with fiber optic technology.

Although the present invention has been described above in terms of specific embodiments, it is anticipated that alterations and modifications thereof will no doubt become apparent to those skilled in the art. It is therefore intended that the following claims be interpreted as covering all such alterations and modifications as fall within the true spirit and scope of the invention.

What is claimed is:

CLAIMS

1. A modulator for modulating incident rays of light, the modulator comprising:

a plurality of equally spaced apart beam elements, each including a light reflective planar surface, the elements being arranged parallel to each other and with the light reflective surfaces of the beam elements being parallel to each other;

means for supporting the beam elements in relation to one another; and

means for moving the beam elements relative to one another between a first configuration wherein the modulator acts to reflect the incident rays of light as a plane mirror, and a second configuration wherein the modulator diffracts the incident rays of light as they are reflected therefrom.

2. A modulator as recited in claim 1, wherein the light reflective surfaces of the beam elements are parallel to each other in both the first and the second configurations.

3. A modulator as recited in claim 2, wherein the perpendicular spacing between the reflective surfaces of adjacent beam elements is equal to m/4 times the wavelength of the incident rays of light, wherein m = an even whole number or zero when the beam elements are in the first configuration and m = an odd number when the beam elements are in the second configuration.

4. A modulator as recited in claim 3, wherein the means for moving the beam elements operates to rotate the beam elements when moving them relative to one another.

5. A modulator as recited in claim 3, wherein alternate beam elements are fixed relative to the support means.

6. A modulator as recited in claim 1, wherein the means for applying force to the beams comprises means for applying an electrostatic force to the beam elements.

7. A modulator as recited in claim 6, wherein the reflective surfaces are formed by metallic layers.

8. A modulator as recited in claim 7, wherein the means for applying electrostatic force includes the metallic layers.

9. A modulator as recited in claim 3, wherein the planar reflective surfaces of the beam elements are equal in dimensions and are substantially rectangular in plan.

10. A modulator as recited in claim 4, wherein the beam elements are resilient.

11. A modulator for modulating a beam of incident light, the modulator comprising;

a planar light reflective surface;

a deformable grating having a planar light reflective surface, the deformable grating being arranged with its reflective surface being parallel to and spaced from the planar reflective surfaces; and

means for moving the grating towards the planar reflective surface while at the same time maintaining the reflective surface of the grating substantially parallel to the planar reflective surface;

whereby, when the perpendicular spacing between the respective light reflective surfaces is equal to m/4 times the wavelength of the incident light and m = an even whole number or zero the modulator acts to reflect the incident light as a plane mirror and when m = an odd whole number the modulator diffracts the incident light as it reflects it, thereby providing the modulation of the beam of light.

12. A modulator as recit d in claim 11, wherein the grating comprises a plurality of equally sized and equally spaced apart parallel rectangular beam elements.

13. A modulator as recited in claim 12, wherein the spacing between each of the beam elements is substantially equal to the transverse width of each of the beam elements.

14. A modulator as recited in claim 13, wherein the spacing between the planar reflective surface and the reflective surface of the deformable grating is equal to half the wavelength of the beam of incident light.

15. A modulator as recited in claim 14, wherein the means for moving the grating towards the planar reflective surface comprises means for applying an electrostatic force between the planar reflective surface and the reflective surface of the grating.

16. A modulator as recited in claim 15, wherein the thickness of each beam element is equal to half the spacing between the two reflective surfaces.

17. A modulator as recited in claim 12 wherein the grating comprises a deformable resilient material.

18. A method of modulating a ray of light, comprising the steps of:

causing the ray to impinge on a plurality of equally spaced apart beam elements, each including a light reflective planar surface, the elements being arranged parallel to each other and with the light reflective surfaces of the beam elements being parallel to each other; and

moving the beam elements relative to one another between a first configuration wherein the modulator acts to reflect the incident rays of light as a plane mirror, and a second configuration wherein the modulator diffracts

the incident rays of light as they are refl cted therefrom.

19. A method of modulating a ray of light as recited in claim 18, wherein the beam elements are moved to cause the perpendicular spacing between the reflective surfaces of adjacent beam elements to be equal to m/4 times the wavelength of the incident rays of light, wherein m = an even whole number or zero when the beam elements are in the first configuration and m = an odd number when the beam elements are in the second configuration.

20. A method as recited in claim 19, wherein the thickness of each beam element is equal to half the spacing between the two reflective surfaces.

21. A method of modulating a ray of light as recited in claim 20, wherein the beam elements are caused to move relative to one another by applying an electrostatic force to the elements.

22. A modulator for modulating incident rays of light, the modulator comprising a plurality of elements arranged to act in concert to modulate the rays by means of diffraction, each element including:

a plurality of equally spaced apart beam elements, each including a light reflective planar surface, the elements being arranged parallel to each other and with the light reflective surfaces of the beam elements being parallel to each other;

means for supporting the beam elements in relation to one another; and

means for moving the beam elements relative to one another between a first configuration wherein the modulator acts to reflect the incident rays of light as a plane mirror, and a second configuration wherein the modulator diffracts the incident rays of light as they are reflected therefrom.

23. A modulator as recited in claim 22, wherein the light reflective surfaces of the beam elements are parallel to each other in both the first and the second configurations.

24. A modulator as recited in claim 23, wherein the perpendicular spacing between the reflective surfaces of adjacent beam elements is equal to m/4 times the wavelength of the incident rays of light, wherein m = an even whole number or zero when the beam elements are in the first configuration and m = an odd number when the beam elements are in the second configuration.

25. A modulator as recited in claim 24, wherein the means for moving the beam elements operates to rotate the beam elements when moving them relative to one another.

26. A modulator as recited in claim 25, wherein alternate beam elements are fixed relative to the support means.

27. A modulator as recited in claim 4, wherein the means for moving the beam elements comprises means for applying an electrostatic force between the planar reflective surface and the reflective surface of the grating.

28. A modulator as recited in claim 27 wherein the beam elements comprise a deformable resilient material.

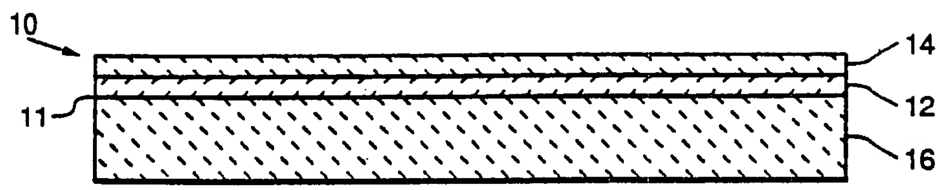

Fig. 1(a)

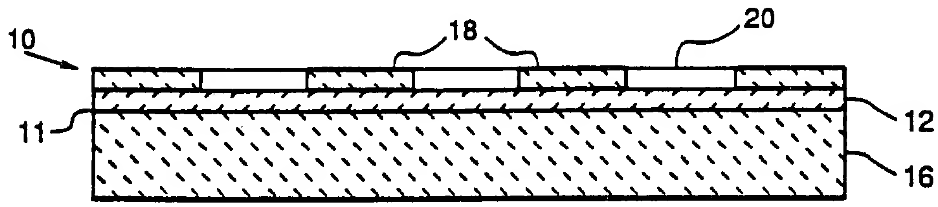

Fig. 1(b)

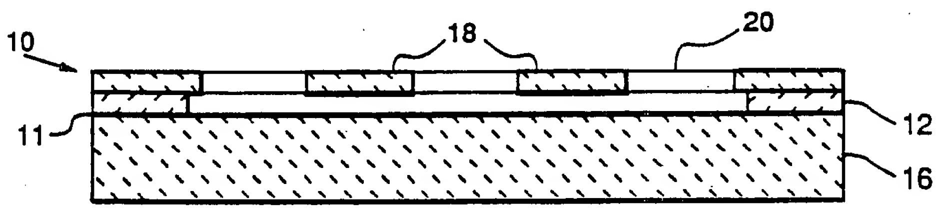

Fig. 1(c)

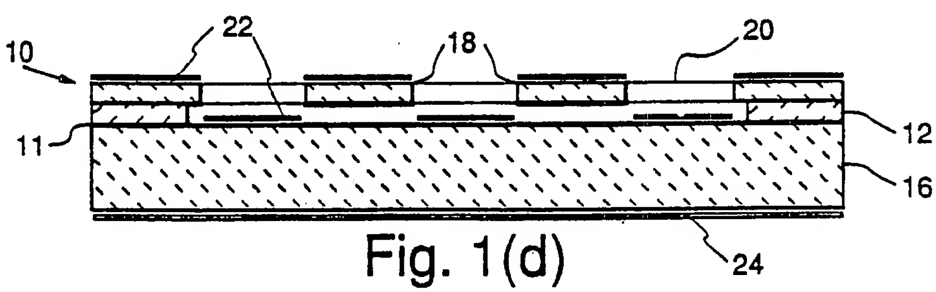

Fig. 1(d)

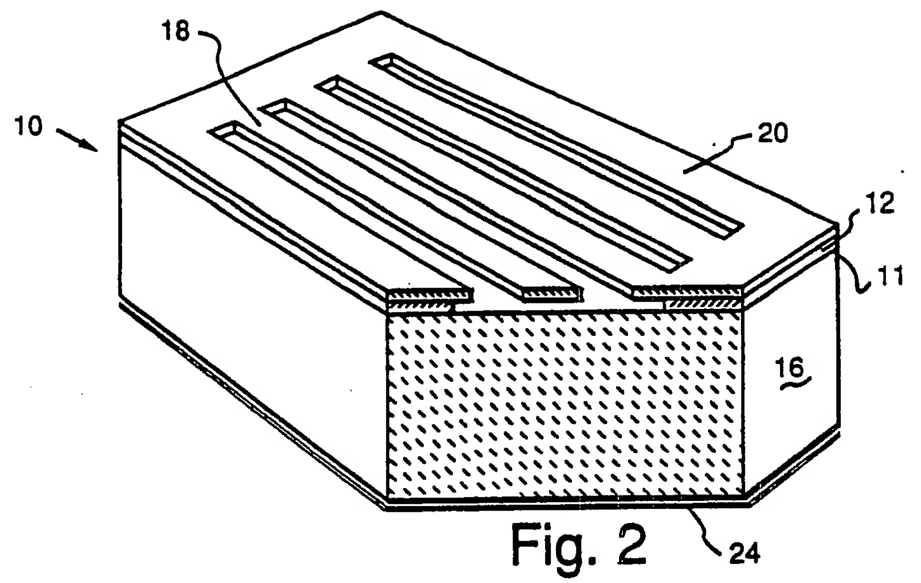

Fig. 2

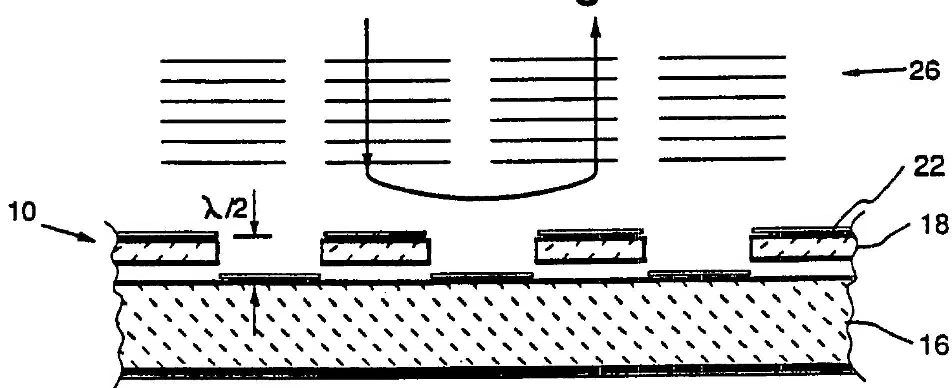

Fig. 3

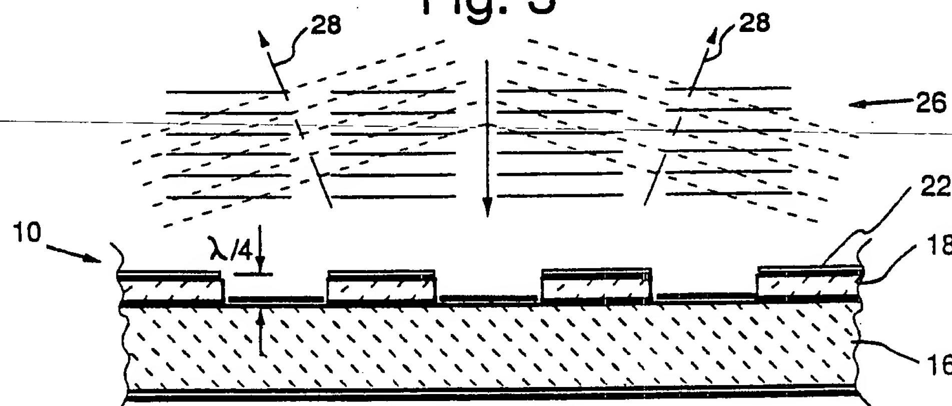

Fig. 4

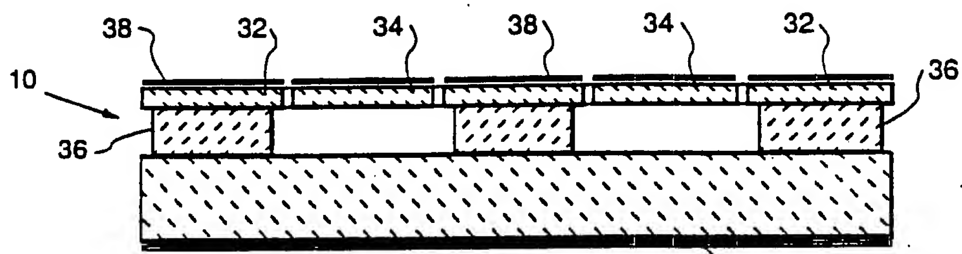

Fig. 5

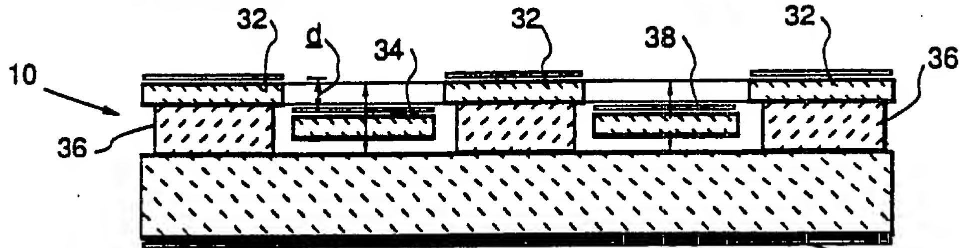

Fig. 6

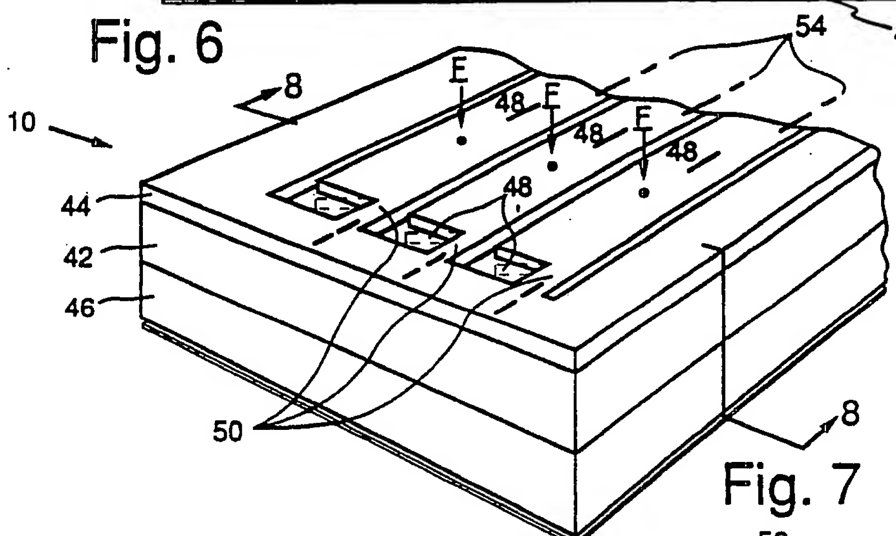

Fig. 7

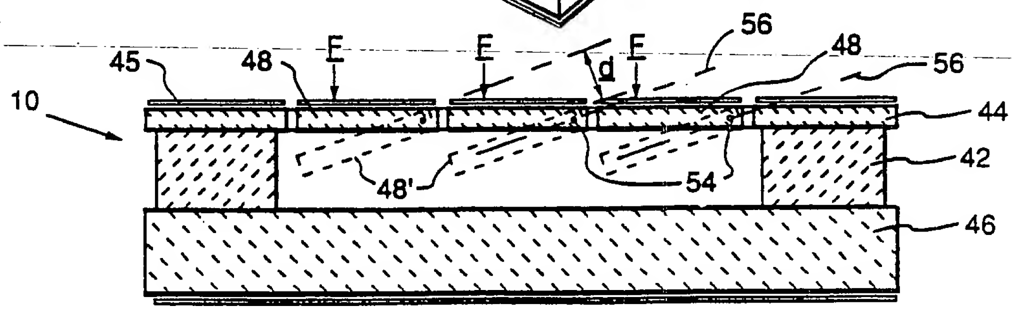

Fig. 8

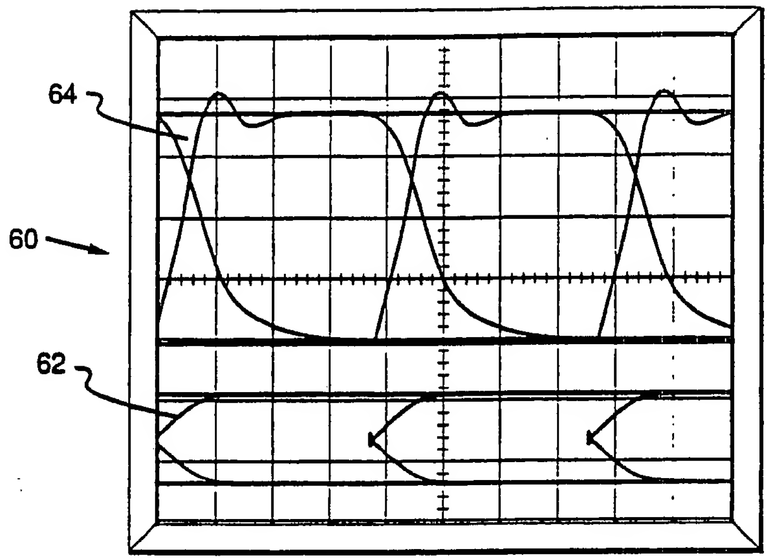

Fig. 9

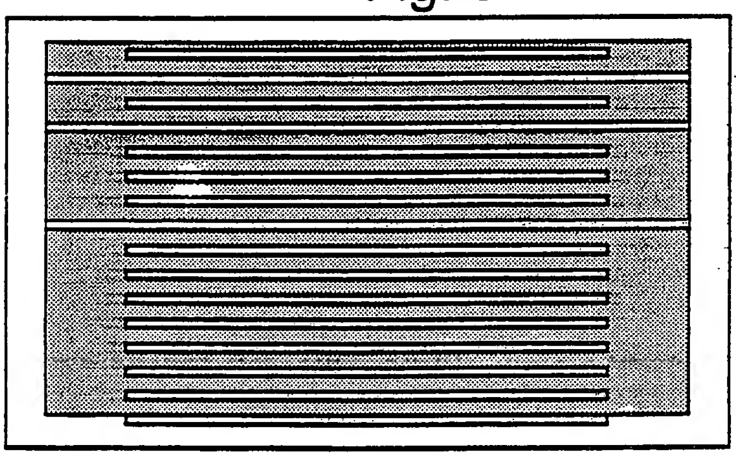

Fig. 10

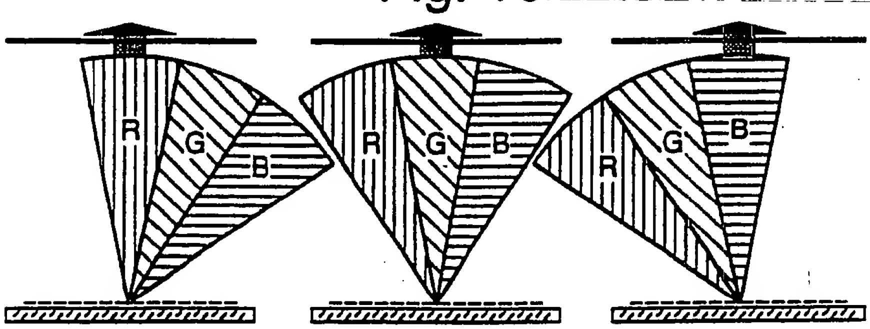

Fig. 11